MOS FET Relays

M-401BY/EY

Analog-switching MOS FET Relay with Dielectric Strength of 5 kVAC between I/O Using Optical Isolation.

- Switches minute analog signals.
- Leakage current of 1 μA max. when output relay is open.
- · RoHS Compliant.

■ Application Examples

- Electronic automatic exchange systems
- Measurement devices
- FA systems



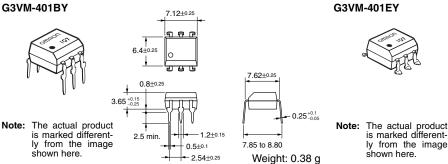
Note: The actual product is marked differently from the image shown here.

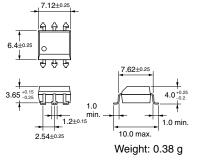
■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	PCB terminals	400 VAC	G3VM-401BY	50	
	Surface-mounting		G3VM-401EY		
	erminals		G3VM-401EY(TR)		1,500

■ Dimensions

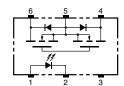
Note: All units are in millimeters unless otherwise indicated.



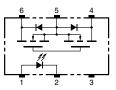


■ Terminal Arrangement/Internal Connections (Top View)

G3VM-401BY

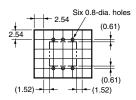


G3VM-401EY



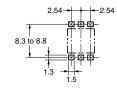
■ PCB Dimensions (Bottom View)

G3VM-401BY



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-401EY

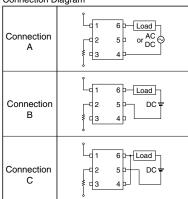


■ Absolute Maximum Ratings (Ta = 25°C)

155 (ltem		Rating	Unit	Measurement conditions
ut LED forward current		I _F	50	mA	
Repetitive peak LED forward current		I _{FP}	1	А	100 μs pulses, 100 pps
LED forward current reduction rate		Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C
LED reverse voltage Connection temperature		V_R	5	V	
		T _j	125	°C	
Load voltage (AC peak/DC)		V_{OFF}	400	V	
Continuous load current ON current reduction rate	Connection A	Io	120	mA	
	Connection B		120		
	Connection C	1	240		
	Connection A	Δ I _{ON} /°C	-1.2	mA/°C	Ta ≥ 25°C
	Connection B	1	-1.2		
	Connection C	1	-2.4		
Connection temperature		T _j	125	°C	
Dielectric strength between input and output (See note 1.)		V _{I-O}	5,000	V_{rms}	AC for 1 min
Operating temperature		T_{α}	-40 to +85	°C	With no icing or condensation
Storage temperature			-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s
	forward current LED forward current LED reverse vo Connection ten Load voltage (A Continuous load current ON current reduction rate Connection ten c strength betw See note 1.) g temperature temperature	forward current LED forward current reduction rate LED reverse voltage Connection temperature Load voltage (AC peak/DC) Continuous load current Connection A Connection C ON current reduction rate Connection B Connection B Connection C Connection C Connection C connection C connection C connection C connection B connection C connection b connection C connection temperature content of the perature co	Repetitive peak LED forward current learned current learned current reduction rate $ \begin{array}{c} I_{FP} \\ I_$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

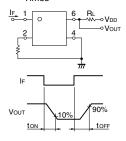
Connection Diagram



■ Electrical Characteristics (Ta = 25°C)

Item			Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions
Input	LED forward voltage		V_F	1.0	1.15	1.3	٧	I _F = 10 mA
	Reverse current		I _R			10	μΑ	V _R = 5 V
	Capacity between terminals		C _T		30		pF	V = 0, f = 1 MHz
	Trigger LED forward current		I _{FT}			3	mA	I _O = 120 mA
Output Maximum resistance with output ON		Connection A	R _{ON}		17	35	Ω	I _F = 5 mA, I _O = 120 mA
	Connection B			11	20	Ω	I _F = 5 mA, I _O = 120 mA	
		Connection C			6	10	Ω	I _F = 5 mA, I _O = 240 mA
	Current leakage when the relay is open		I _{LEAK}		0.0004	1.0	μΑ	V _{OFF} = 400 V
		C _{OFF}		40		pF	V = 0, f = 1MHz	
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, V _s = 0 V	
Insulation resistance		R _{I-O}	1,000			ΜΩ	$\begin{aligned} &V_{\text{I-O}} = 500 \text{ VDC}, \\ &R_{\text{oH}} \leq 60\% \end{aligned}$	
Turn-ON time		t _{ON}		0.3	1.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega,$	
Turn-OFF time		t _{OFF}		0.1	1.0	ms	$V_{DD} = 20 \text{ V (See note 2.)}$	

Note: 2. Turn-ON and Turn-OFF Times



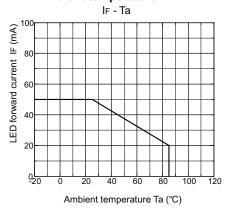
■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

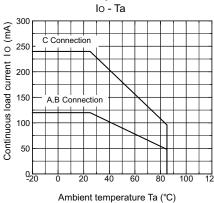
Item	Symbol	Minimum	Typical	Maximum	Unit
Load voltage (AC peak/DC)	$V_{\Delta\Delta}$			320	V
Operating LED forward current	I_{Φ}	5	7.5	25	mA
Continuous load current (AC peak/DC)	Io			120	mA
Operating temperature	T_{α}	- 20		65	°C

■ Engineering Data

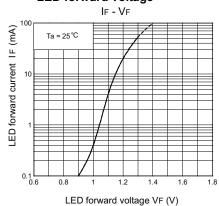
LED forward current vs. Ambient temperature



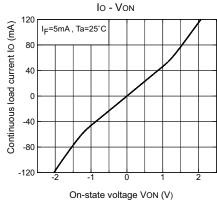
Continuous load current vs. Ambient temperature



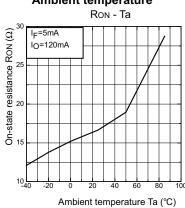
LED forward current vs. LED forward voltage



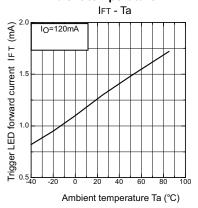
Continuous load current vs. On-state voltage



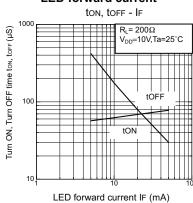
On-state resistance vs. Ambient temperature



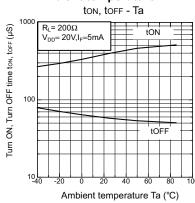
Trigger LED forward current vs. Ambient temperature



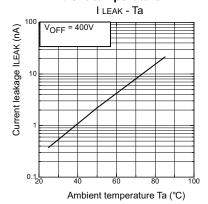
Turn ON, Turn OFF time vs. LED forward current



Turn ON, Turn OFF time vs. Ambient temperature



Current leakage vs. Ambient temperature





All sales are subject to Omron Electronic Components LLC standard terms and conditions of sale, which can be found at http://www.components.omron.com/components/web/webfiles.nsf/sales_terms.html

ALL DIMENSIONS SHOWN ARE IN MILLIMETERS.To convert millimeters into inches, multiply by 0.03937. To convert grams into ounces, multiply by 0.03527.

OMRON **OMRON ELECTRONIC**

COMPONENTS LLC 55 E. Commerce Drive, Suite B Schaumburg, IL 60173

847-882-2288

Cat. No. X302-E-1

12/10

OMRON ON-LINE

Global - http://www.omron.com USA - http://www.components.omron.com

Specifications subject to change without notice Printed in USA

MOS FET Relays **G3VM-401BY/EY**